

Andreev current enhancement and subgap conductance of superconducting hybrid structures in the presence of a small spin-splitting field

A. Ozaeta,¹ A. S. Vasenko,² F. W. J. Hekking,³ and F. S. Bergeret^{1,4}

¹*Centro de Física de Materiales (CFM-MPC), Centro Mixto CSIC-UPV/EHU, Manuel de Lardizabal 4, E-20018 San Sebastián, Spain*

²*Institut Laue-Langevin, 6 rue Jules Horowitz, BP 156, 38042 Grenoble, France*

³*LPMMC, Université Joseph Fourier and CNRS, 25 Avenue des Martyrs, BP 166, 38042 Grenoble, France*

⁴*Donostia International Physics Center (DIPC), Manuel de Lardizabal 5, E-20018 San Sebastián, Spain*

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We investigate the subgap transport properties of a S-F-N_e structure. Here S (N_e) is a superconducting (normal) electrode, and F is either a ferromagnet or a normal wire in the presence of an exchange or a spin-splitting Zeeman field respectively. By solving the quasiclassical equations we first analyze the behavior of the subgap current, known as the Andreev current, as a function of the field strength for different values of the voltage, temperature and length of the junction. We show that there is a critical value of the bias voltage V^* above which the Andreev current is enhanced by the spin-splitting field. This unexpected behavior can be explained as the competition between two-particle tunneling processes and decoherence mechanisms originated from the temperature, voltage and exchange field respectively. We also show that at finite temperature the Andreev current has a peak for values of the exchange field close to the superconducting gap. Finally, we compute the differential conductance and show that its measurement can be used as an accurate way of determining the strength of spin-splitting fields smaller than the superconducting gap.

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Introduction- Transport properties of hybrid structures consisting of superconducting and non-superconducting materials have been studied extensively in the last decades¹. In particular, there is a renewed interest in the study of the subgap conductance of superconducting hybrid structures in the presence of Zeeman-like fields in view of the presumable detection of Majorana Fermions². Intuitively, due to the gap Δ in the density of states of a superconductor the charge transport through a superconductor-normal (S-N) metal junction is expected to vanish for voltages smaller than Δ . However, this is not always the case. Experiments on S/N structures have shown a finite subgap conductance³. This behavior was discussed theoretically in Refs. 4 and 5. It was shown that the conductance of a S-N-N_e structure, where N_e denotes a normal metal electrode, shows a peak at a voltage smaller than the superconducting gap⁶ in the case of finite S/N barrier resistances or if N is a diffusive metal^{4,5}. A similar behavior was predicted if one substitutes the normal by a ferromagnetic metal (F)⁷⁻⁹. In all these examples, the key mechanism to explain the finite subgap conductance is the Andreev reflection^{10,11} which takes place at the S/N and S/F interfaces and allows the flow of an electric current even for voltages smaller than the superconducting gap Δ . By this process an electron from the normal region is reflected as a hole forming a coherent electron-hole pair which penetrates into a diffusive normal region over distances of the order of the thermal length $\sqrt{\mathcal{D}/T}$, where \mathcal{D} is the diffusion coefficient and T is the temperature (here and below we set $\hbar = k_B = 1$). This mechanism leads to a finite condensate density in the normal metal, i.e. to the so called superconducting proximity effect.

At a S/F interface the mechanism of charge transport is however modified since the incoming electron and reflected hole belong to different spin bands¹². Thus, one expects a suppression of the Andreev current by increasing the exchange

field h of the ferromagnet, which is a measure for the spin-splitting at the Fermi level. In the ferromagnet the coherence length of the electron-hole pairs is given by the minimum between the thermal and the magnetic ($\sim \sqrt{\mathcal{D}/h}$) lengths. One expects that by increasing the strength of the field h the electron-hole coherence would be suppressed and hence the subgap current reduced. As we show below, this intuitive picture does not hold always.

In this Letter we analyze the Andreev current and conductance through a S-F-N_e hybrid structure as a function of the field h . Here h denotes either the intrinsic exchange field of a ferromagnet or a spin-splitting field in a normal metal caused by either an external magnetic field or the proximity of an insulating ferromagnet¹³. We focus our study on weak fields, $h \leq \Delta$ and $h \gtrsim \Delta$. We find an interesting interplay between phase-coherent diffusive propagation of Andreev pairs due to the proximity effect and decoherence mechanisms originated from the temperature, voltage and exchange field respectively. This interplay leads to a non-monotonic behavior of the transport properties as a function of h . For very low temperatures and voltages $eV \ll \Delta$ the Andreev current decays monotonically by increasing h as expected. If one keeps the voltage low but now increases the temperature, the Andreev current shows a peak at $h \approx \Delta$. An unexpected behavior is obtained when the voltage exceeds some critical value V^* . In this case, the Andreev current is enhanced by the field h reaching a maximum at $h \approx eV$. We show that the value of V^* depends on the length of the F wire and the temperature. In particular, for zero-temperature and in the long-junction limit, i.e. when the length of F is much larger than the coherence length, we show that $eV^* \approx 0.56\Delta_0$, where Δ_0 is the value of Δ at $T = 0$. We also compute the subgap conductance of the system at low temperatures and small fields $h < \Delta$. We show that it has a peak at $eV = h$. Thus, transport measurements of this type

can be used to determine the strength of a weak exchange or Zeeman-like field in the nanostructure.

Model and basic equations- We consider a ferromagnetic wire F. Its length, L is smaller than the inelastic relaxation length. The wire is attached at $x = 0$ to a superconducting (S) and at $x = L$ to a normal (N_e) electrode. As noticed above, F can also describe a normal wire in a spin-splitting field B (in which case $h = \mu_B B$, where μ_B is the Bohr magneton) or in proximity with an insulating ferromagnet¹³. We consider the diffusive limit, i.e. we assume that the elastic scattering length is much smaller than the decay length of the superconducting condensate into the F region. In order to describe the transport properties of the system we compute the quasiclassical Green functions^{14,15}. They obey the Usadel equation¹⁶ that in the so called θ - parametrization reads¹⁵

$$\partial_{xx}^2 \theta_{\pm} = 2i \frac{E \pm h}{\mathcal{D}} \sinh \theta_{\pm}. \quad (1)$$

Here the upper (lower) index denotes the spin-up (down) component. The normal and anomalous Green functions are given by $g_{\pm} = \cosh \theta_{\pm}$ and $f_{\pm} = \sinh \theta_{\pm}$ respectively. Because of the high transparency of the F/ N_e interface the functions θ_{\pm} vanish at $x = L$, i.e. superconducting correlations are negligible at the F/ N_e interface. We consider a tunneling barrier at the S/F interface and assume that its tunneling resistance R_T is much larger than the normal resistance R_F of the F layer. Thus, by voltage-biasing the N_e the voltage drop takes place at the S/F tunnel interface. To leading order in $R_F/R_T \ll 1$ the Green functions obey the Kupriyanov-Lukichev boundary condition at $x = 0$ ¹⁷

$$\partial_x \theta_{\pm}|_{x=0} = \frac{R_F}{LR_T} \sinh[\theta_{\pm}|_{x=0} - \theta_S], \quad (2)$$

where $\theta_S = \text{arctanh}(\Delta/E)$ is the superconducting bulk value of the function θ . Once the functions θ_{\pm} are obtained one can compute the current through the junction. In particular, we are interested in the Andreev current, i.e. the current for voltages smaller than the superconducting gap due to Andreev processes at the S/F interface. Such current is given by the expression^{5,18}

$$I_A = \sum_{j=\pm} \int_0^{\Delta} \frac{n_-(E) dE/2eR_T}{2W\alpha_j(E) - \sqrt{1 - (E/\Delta)^2} \text{Im}^{-1}(\sinh \theta_j|_{x=0})}, \quad (3)$$

where $n_-(E) = \frac{1}{2}(\tanh[(E + eV)/2T] - \tanh[(E - eV)/2T])$ is the quasiparticle distribution function in the N_e electrode, $\alpha_{\pm}(E) = (1/\xi) \int_0^L dx \cosh^{-2}[\text{Re} \theta_{\pm}(x)]$, $W = \xi R_F/2LR_T$ is the diffusive tunneling parameter^{17,19}, and $\xi = \sqrt{\mathcal{D}/2\Delta}$ is the superconducting coherence length. Eq. (3) is the expression used throughout this article in order to determine the subgap charge transport²⁰.

Results- We first compute the Andreev current numerically by solving Eqs. (1-3). In Fig. 1 we show the dependence of the Andreev current on the exchange field h for different values of the bias voltage and temperature for a ferromagnetic F wire of the length $L = 10\xi$.

We consider first the zero-temperature limit. For small enough voltages (e.g. $eV = 0.3\Delta$, black solid line in Fig. 1b)

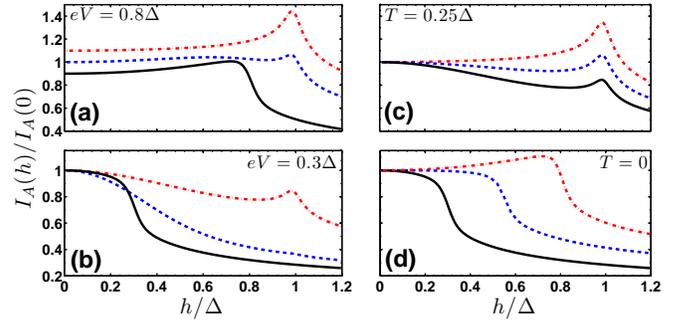


FIG. 1. (Color online) The h -dependence of the ratio $I_A(h)/I_A(0)$ for $L = 10\xi$ and $W = 0.007$. Left panels correspond to (a) $eV = 0.8\Delta$ and (b) $eV = 0.3\Delta$. The different curves are for $T = 0$ (black solid line), $T = 0.12\Delta_0$ (blue dashed line) and $T = 0.25\Delta_0$ (red point-dashed line). The right panels corresponds to (c) $T = 0.25\Delta_0$ and (d) $T = 0$, while the different curves to $eV = 0.3\Delta$ (black solid line), $eV = 0.55\Delta$ (blue dashed line) and $eV = 0.8\Delta$ (red point-dashed line). In the (a) panel curves are vertically shifted with respect to each other for clarity.

the Andreev current decays monotonously with increasing h . This behavior is the one expected, since by increasing h the coherence length of the Andreev pairs in the normal region is suppressed, leading to a reduction of the subgap current. For large enough voltages (e.g. $eV = 0.8\Delta$ in Fig. 1) and keeping the temperature low, the Andreev current first increases by increasing h , reaches a maximum at $h \approx eV$, and then drops by further increase of the exchange field, as it is shown for example by the black solid line in Fig. 1a. A common feature of all the low-temperature curves in Fig. 1 is the sharp suppression of the Andreev current at $h \approx eV$.

For large enough temperatures ($T = 0.25\Delta_0$ in Fig. 1c) one observes a peak at $h \approx \Delta$ [Fig. 1(c)]. The relative height of this peak increases with temperature and voltage as one sees in Figs. 1a and 1c respectively. In the case of large enough values of V and T , one is able to observe both the enhancement of the Andreev current by increasing h and the peak at $h \approx \Delta$ (see for example blue dashed line in Fig 1a). For values of the exchange field larger than Δ , the Andreev current decreases by increasing h in all cases. In principle all the behaviors of the Andreev current can be observed by measuring the full electric current through the junction as the single particle current is almost independent of h .

In order to give a physical interpretation of these results, we first recall the details of the process of two-electron tunneling that gives rise to subgap current⁴ in diffusive systems in the absence of an exchange field. The value of this current is governed by two competing effects. On the one hand, the origin of the subgap current is the tunneling from the normal metal to the superconductor of two electrons with energies ξ_{k_1} and ξ_{k_2} , respectively and momenta k_1 and k_2 , that form a Cooper pair. This process is of the second order in tunneling and therefore involves a virtual state with an excitation on both sides of the tunnel barrier. The relevant virtual state energies are given by the difference $E_k - \xi_{k_1, k_2}$, where $E_k = \sqrt{\Delta^2 + \xi_k^2}$ is the excitation energy of a quasiparticle with the momentum

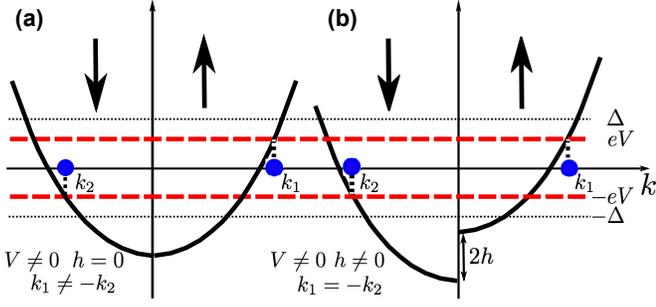


FIG. 2. (Color online) Schematic energy diagram for a non magnetic (a) and magnetic (b) metal. The thick solid parabolas are the dispersions of free electrons with spin up (\uparrow) and spin-down (\downarrow). The k axis corresponds to the Fermi level in the superconductor. We consider quasi-electrons and -holes with energies $\pm eV < \Delta$ and momentum $k_{1,2}$. Time-reversal pairing requires that $k_1 = k_2$. In case of a normal metal [panel (a)] this condition is satisfied only for $eV = 0$ while for a ferromagnet ($h \neq 0$) if $h = eV$.

k in the superconductor. Typical values of ξ_k are T or eV . Hence under subgap conditions $T, eV \ll \Delta$, the virtual state energy is typically given by the superconducting gap Δ . However, when these characteristic energies become larger and approach the value of the gap, the difference $E_k - \xi_{k_1, k_2}$ eventually vanishes. As a result, the amplitude for two-electron tunneling increases drastically, leading to a strong increase of the Andreev current, accompanied by the onset of single-particle tunneling at energies above the gap Δ . On the other hand, two-electron tunneling is a coherent process: the main contribution to two-electron tunneling stems from two nearly time-reversed electrons $k_1 \simeq -k_2$ located in an energy window of width $\delta\varepsilon \sim eV, T$ close to the Fermi energy, diffusing phase-coherently over a typical distance $L_{coh} = \sqrt{\mathcal{D}/(\delta\varepsilon)}$ in the normal metal before tunneling⁴. This coherence length decreases upon increasing the characteristic energies $\delta\varepsilon \simeq eV, T$, thereby decreasing the Andreev current.

We now turn to the effect of the exchange field h on two-electron tunneling. If h is nonzero, the majority and minority spin electrons at the Fermi level are characterized by different wave vectors $k_{F,\pm} = k_F \mp \delta k$, where $\delta k \sim h/v_F$ and v_F is the Fermi velocity. In Fig. 2 we show a schematic energy diagram. The wave vectors $k_{F,\pm}$ are determined by intersection between the parabolas and the k -axis. For a given value of $eV \lesssim \Delta$ and in the absence of an exchange field the relevant excitations with energies $\sim \pm eV$ and wave vectors $k_{1,2}$ are not time-reversed (see Fig. 2a) and therefore their contribution to the current is not coherent. However upon increasing h , $|k_1| \rightarrow |k_2|$, *i.e.* the relevant excitations become more and more coherent, leading to an additional increase of two-electron tunneling. In particular when $h = eV$, $k_1 = -k_2$ (*cf.* Fig. 2b). If $T \rightarrow 0$ there are no occupied states for $\xi_k > eV$. Consequently as soon as $h > eV$, the energy window around the Fermi level does not contain time-reversed electrons. This leads to the drop of the Andreev current shown for example in Fig. 1d. In contrast, for finite values of T , there are thermally induced quasiparticles with energy $\sim \Delta$, that become exactly time-reversed whenever $h = \Delta$. This leads to the maximum of

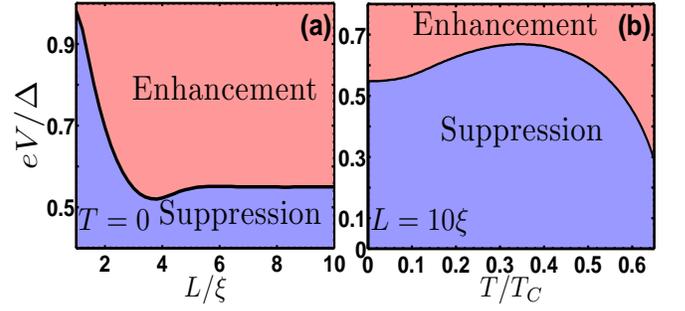


FIG. 3. (Color online) Voltage-junction length (a) and voltage-temperature (b) diagrams. The black solid line represents the values of eV^*/Δ . For the range of parameters situated below this line the Andreev current decreases in the presence of a small exchange field (suppression), while in the region above the line the current increases (enhancement). We set $W = 0.007$ in both panels, $T = 0$ in panel (a) and $L = 10\xi$ in panel (b).

the current at $h = \Delta$ when the temperature is finite (*cf.* Fig. 1c). The effects are most clearly seen when plotting the ratio $I_A(h)/I_A(0)$, as the Andreev pair decoherence effects due to temperature or voltage are then divided out.

A more quantitative understanding of the effects discussed above can be get by analyzing some limiting cases in which simple analytical expressions for the current can be derived. We first focus our analysis on the zero-temperature limit. Due to the tunneling barrier at the S/F interface the proximity effect is weak and hence one can linearize Eqs. (1-2) with respect to $R_F/R_T \ll 1$. After a straightforward calculation one obtains the Andreev current in this limit,

$$I_A = \frac{W\Delta_0^2}{2eR_T} \sum_{j=\pm} \int_0^{eV} \frac{dE}{\Delta_0^2 - E^2} \times \text{Re} \left[\sqrt{\frac{i\Delta_0}{E + jh}} \tanh \left(\sqrt{\frac{E + jh}{i\Delta_0}} \frac{L}{\xi} \right) \right]. \quad (4)$$

For a large exchange field, $h \gg \Delta_0 > eV$ one can evaluate this expression obtaining

$$I_A \approx \frac{R_F \Delta_0}{8eLR_T^2} \sqrt{\frac{\mathcal{D}}{h}} \log \left[\frac{\Delta_0 + eV}{\Delta_0 - eV} \right]. \quad (5)$$

Thus, the Andreev current decays as $h^{-1/2}$ for large values of h in accordance with our numerical results (see Fig. 1).

In the case of small values of h , $h \lesssim eV < \Delta_0$, one can evaluate Eq. (4) in the long-junction limit, *i.e.* when $L \gg \sqrt{\mathcal{D}/h}$. In this case the Andreev current reads

$$I_A = \frac{\Delta_0 \xi R_F}{eLR_T^2} \sum_{j=\pm} \frac{\text{arctanh} \left(\sqrt{\frac{eV + jh}{\Delta_0 + jh}} \right) + \arctan \left(\sqrt{\frac{eV - jh}{\Delta_0 + jh}} \right)}{\sqrt{\Delta_0 + jh}}. \quad (6)$$

This expression describes the two different behaviors obtained in Fig. 1 for $h \leq eV$. For small voltages I_A decreases by increasing the field h . However, for large enough values of the voltage I_A is enhanced by the presence of the field. From Eq. (6) we can determine the voltage V^* , at which the

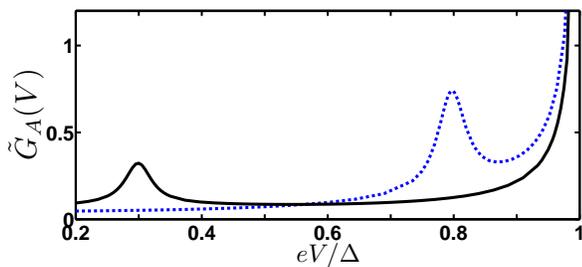


FIG. 4. (Color online) The bias voltage dependence of differential conductance at $T = 0$ for fields: $h = 0.3$ (black solid) and $h = 0.8$ (blue dashed). Here $\tilde{G}_A = 4R_T G_A$, $W = 0.007$ and $L = 10\xi$.

crossover between these two behaviors takes place, by expanding the expression for the current up to second order in $h/eV \ll 1$, *i.e.* up to the first non-vanishing correction to I_A due to the exchange field. This expansion leads to the following transcendental expression which determine the voltage V^* at which the crossover takes place,

$$\left(\frac{\Delta_0}{eV^*}\right)^{3/2} = \frac{3}{2} \left(\operatorname{arctanh} \sqrt{eV^*/\Delta_0} + \arctan \sqrt{eV^*/\Delta_0} \right). \quad (7)$$

From here we get $eV^* \approx 0.56\Delta_0$. For $V < V^*$ the Andreev current decays monotonically with h while for $V > V^*$ it increases up to a maximum value at $h \lesssim eV$. This is in agreement with our numerical results in Fig. 1.

For an arbitrary length L and finite temperature we have computed the value of V^* numerically. In Fig. 3 we show the results. The solid black line gives the values of V^* as a function of L and T [the (a) and (b) panels of Fig. 3 respectively]. The area below the black curve corresponds to the range of parameters for which the Andreev current is suppressed by the presence of a spin-splitting field, while the area above the solid line corresponds to the range of parameters for which the unexpected enhancement of the subgap current takes place. According to Fig. 3(a) at $T = 0$ the value of V^* first decreases as L increases, reach a minimum and then grows again up to the asymptotic value $eV^* \approx 0.56\Delta_0$. Also the dependence of V^* on the temperature is non-monotonic having a maximum value at $T \sim 0.2\Delta_0$.

Small spin-splitting fields, as those studied in the present work, can be created by applying an external magnetic field B , in which case $h = \mu_B B$ or by the proximity of a ferromagnetic insulator as discussed in Ref. 13. It may be also an intrinsic exchange field of weak ferromagnetic alloys (see, for example, Ref. 21). Such small exchange fields are in principle dif-

ficult to detect. However, as we show in Fig. 4, by measuring the subgap differential conductance $G = dI/dV$ at low temperatures, one can accurately determine the value of h . At $T = 0$ the conductance shows two well defined peaks, one at $eV = h$ and the other at $eV = \Delta$. These are related to a sudden increase of the coherence length between the electron-hole pairs in the ferromagnet and of the two-particle tunneling amplitude respectively. As we have seen above, at small voltages $eV < h$ electrons with majority spins do not find time-reversed partners in the narrow energy window around the Fermi energy, *i.e.* such pairs show weak coherence. By increasing the voltage $eV \lesssim h$, the contribution of time-reversed electrons to the current gradually increases and consequently the differential conductance increases, reaching a maximum at $eV = h$. Further increase of the voltage, $eV > h$, leads to an increasing contribution to the current from non time-reversed electron-hole pairs and therefore to a suppression of the coherent contribution to G . At $h < eV \lesssim \Delta$ the two-electron tunneling amplitude increases as $(eV - \Delta)^{-1}$ due to virtual state contributions with energies eV close to the gap; as a result the conductance shows a sharp increase. For $h \rightarrow 0$ (normal metal) the peak moves toward $eV \rightarrow 0$ (not shown here), which corresponds to the zero bias peak discussed, for example, in Ref. 22.

In conclusion, we present an exhaustive study of the subgap charge current through S-F-N₀ hybrid structures in the presence of a spin-splitting field. We have demonstrated the existence of a threshold bias voltage V^* above which the Andreev current can be enhanced by an exchange field. We also have shown that at finite temperatures the Andreev current has a peak for values of the exchange field close to the superconducting gap Δ . Finally, we have proposed a way to determine the strength of small exchange fields by measuring the differential conductance. Beyond the fundamental interest, our results can also be useful for the implementation of a recent and interesting proposal¹³ which suggests a way to detect the odd-triplet component²³ of the superconducting condensate induced in a normal metal in contact with a superconductor and a ferromagnetic insulator. The latter induces an effective exchange field in the normal region. The amplitude of such induced exchange fields is smaller than the superconducting gap²⁴. Therefore the proposed ferromagnet proximity system in Ref. 13 is a candidate to observe the phenomena described in the present work.

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⁶ Throughout this article Δ denotes the temperature dependent BCS gap, while Δ_0 its value at $T = 0$.

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